

MOS FIELD EFFECT TRANSISTOR

3SK224

RF AMPLIFIER FOR UHF TV TUNER N-CHANNEL SI DUAL GATE MOS FIELD-EFFECT TRANSISTOR 4 PINS MINI MOLD

FEATURES

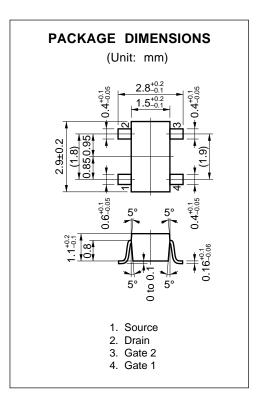
Low Noise Figure: NF = 1.8 dB TYP. (f = 900 MHz)
 High Power Gain: GPS = 17 dB TYP. (f = 900 MHz)

Suitable for use as RF amplifier in UHF TV tuner.
 Automatically Mounting: Embossed Type Taping
 Small Package: 4 Pins Mini Mold

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

VDSX	18	V
V _{G1} S	±8 (±10)*1	V
V _{G2} S	±8 (±10)*1	V
V_{G1D}	18	V
V_{G2D}	18	V
lσ	25	mA
PD	200	mW
T_ch	125	°C
Tstg	-55 to +125	°C
	VG1S VG2S VG1D VG2D ID PD Tch	VG1S ±8 (±10)*1 VG2S ±8 (±10)*1 VG1D 18 VG2D 18 ID 25 PD 200 Tch 125

*1 $R_L \ge 10 \ k\Omega$





ELECTRICAL CHARACTERISTICS (TA = 25 $^{\circ}$ C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain to Source Breakdown Voltage	BV _{DSX}	18			V	$V_{G1S} = V_{G2S} = -2 \text{ V, ID} = 10 \ \mu\text{A}$	
Drain Current	IDSX	0.5		15.0	mA	VDS = 6 V, VG2S = 3 V, VG1S = 0.5 V	
Gate1 to Source Cutoff Voltage	V _{G1S(off)}	-1.5		+0.5	V	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}, I_{D} = 10 \mu A$	
Gate2 to Source Cutoff Voltage	V _{G2S(off)}	-1.0		+1.0	V	$V_{DS} = 6 \text{ V}, V_{G1S} = 3 \text{ V}, I_{D} = 10 \mu A$	
Gate1 Reverse Current	I _{G1SS}			±20	nA	V _{DS} = 0, V _{G2S} = 0, V _{G1S} = ±8 V	
Gate2 Reverse Current	l _{G2SS}			±20	nA	V _{DS} = 0, V _{G1S} = 0, V _{G2S} = ±8 V	
Forward Transfer Admittance	yfs	18	22		mS	V _{DS} = 5 V, V _{G2S} = 4 V, I _D = 10 mA f = 1 kHz	
Input Capacitance	Ciss	1.2	1.7	2.2	pF	V _{DS} = 6 V, V _{G2S} = 3 V, I _D = 10 mA	
Output Capacitance	Coss	0.5	0.9	1.2	pF	f = 1 MHz	
Reverse Transfer Capacitance	Crss		0.015	0.025	pF		
Power Gain	Gps	15.0	17.0		dB	V _{DS} = 6 V, V _{G2S} = 3 V, I _D = 10 mA	
Noise Figure	NF		1.8	2.5	dB	f = 900 MHz	

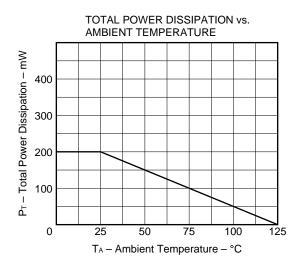
IDSX Classification

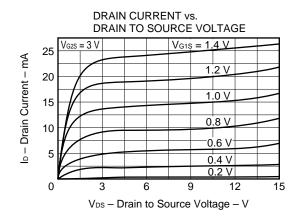
Class	U94/UID*	U95/UIE*
Marking	U94	U95
IDSX (mA)	0.5 to 7.0	5.0 to 15.0

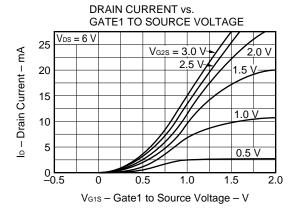
^{*} Old Specification/New Specification

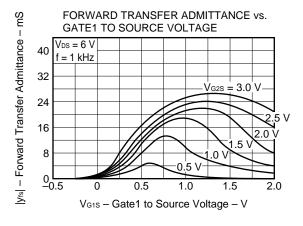
PRECAUTION: Avoid high static voltages or electric fields so that this device would not suffer from any damage due to those voltage or fields.

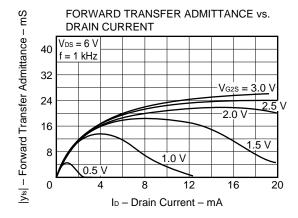
TYPICAL CHARACTERISTICS (TA = 25 °C)

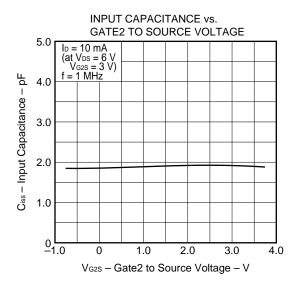




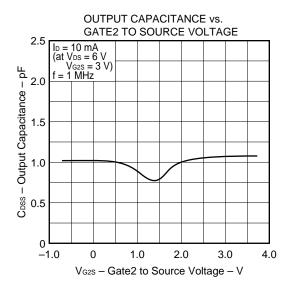


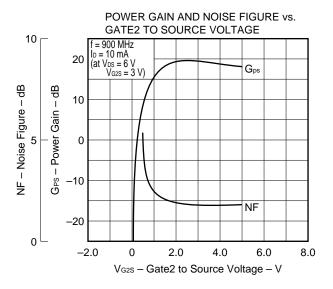




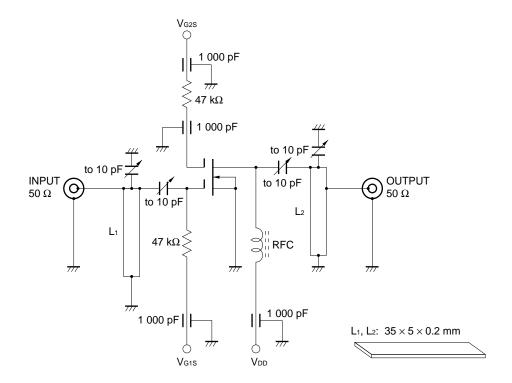








900 MHz GPS & NF TEST CIRCUIT



[MEMO]

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Anti-radioactive design is not implemented in this product.

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